



#10/Amend A
524-02
Jal

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: ITOH, AKIO

Group Art Unit: 2815

Serial No.: 09/594,091

Examiner: Matthew Warren

Filed: June 15, 2000

FOR: SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

AMENDMENT UNDER 37 CFR §1.111

Commissioner for Patents
Washington, D.C. 20231

May 17, 2002

Sir:

In response to the Office Action dated **March 15, 2002**, please amend the above-identified application as follows:

IN THE TITLE:

Please amend the title to read: "A Semiconductor Device with More Than One Impurity Region"

IN THE CLAIMS:

Please amend the claims as follows:

1. (Amended) A semiconductor device comprising;
a transistor having a first impurity region and a second impurity region formed on a semiconductor substrate, and a gate electrode formed on the semiconductor substrate;
a first insulating film for covering the transistor;

RECEIVED
MAY 21 2002
TECHNOLOGY CENTER 2800

A. J. S. B. 1